



# N-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)			
	0.033 at V <sub>GS</sub> = 4.5 V	4.9			
20	0.040 at V <sub>GS</sub> = 2.5 V	4.4			
	0.051 at V <sub>GS</sub> = 1.8 V	3.9			

### **FEATURES**

 Halogen-free According to IEC 61249-2-21 Available



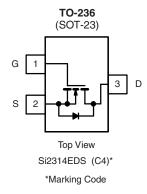
ESD Protected: 3000 V



**FREE** 

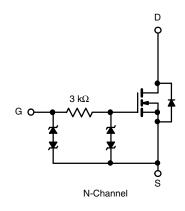
### **APPLICATIONS**

• LI-Ion Battery Protection



Ordering Information: Si2314EDS-T1-E3 (Lead (Pb)-free)

Si2314EDS-T1-GE3 (Lead (Pb)-free and Halogen-free)



Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	20		V
Gate-Source Voltage		$V_{GS}$	± 12		
Continuous Drain Current /T 150 °C\a	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	4.9	3.77	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		3.9	3.0	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	15		Α
Avalanche Current <sup>b</sup>	L = 0.1 mH	I <sub>AS</sub>	15 11.25		
Single Avalanche Energy	L = 0.1 IIII1	E <sub>AS</sub>			mJ
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	1.0		Α
Decree Discipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	1.25	0.75	W
Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		0.80	0.48	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55	to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 5 s	В	75	100		
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	$R_{thJA}$	120	166	°C/W	
Maximum Junction-to-Foot	Steady State	$R_{thJF}$	40	50		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. Pulse width limited by maximum junction temperature.

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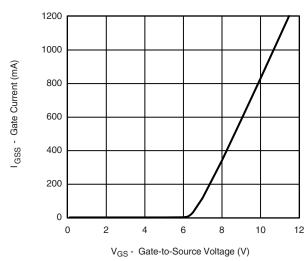
			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu A$	20			V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	0.45		0.95	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 1.5		
Zoro Cata Valtaga Drain Current	l	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V			1	μΑ	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			75		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 10 \text{ V}, V_{GS} = 4.5 \text{ V}$	15			Α	
		$V_{GS} = 4.5 \text{ V}, I_D = 5.0 \text{ A}$		0.027	0.033	Ω	
Drain-Source On-Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, I_D = 4.5 \text{ A}$		0.033	0.040		
		$V_{GS} = 1.8 \text{ V}, I_D = 4.0 \text{ A}$		0.042	0.051	1	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 5.0 \text{ A}$		40		S	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = 1.0 A, V <sub>GS</sub> = 0 V		0.8	1.2	٧	
Dynamic <sup>b</sup>				•	'		
Total Gate Charge	$Q_g$			11.0	14.0	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 5.0 \text{ A}$		1.5			
Gate-Drain Charge	$Q_{gd}$			2.1			
Switching	•			•	'		
Turn-On Delay Time	t <sub>d(on)</sub>			0.53	0.8		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 10 $\Omega$		1.4	2.2	- μs	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 1.0 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 6 \Omega$		13.5	20		
Fall Time	t <sub>f</sub>			5.9	9		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.0 A, dI/dt = 100 A/μs		13	25	ns	

### Notes:

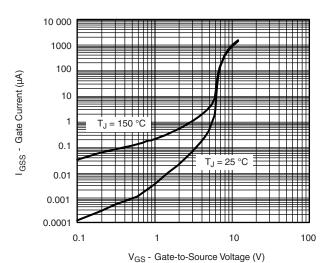
- a. Pulse test: PW  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Gate-Current vs. Gate-Source Voltage

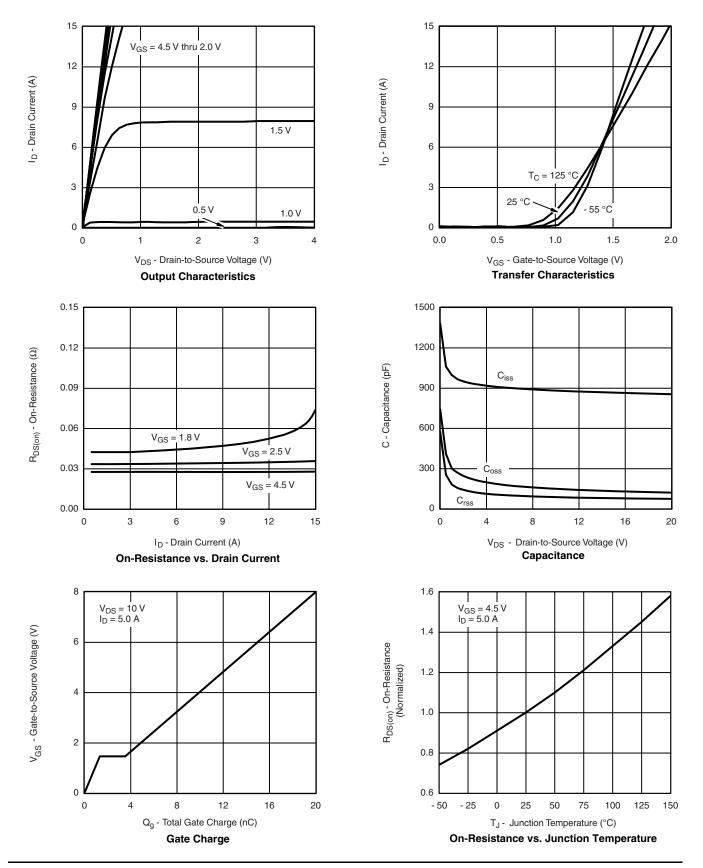








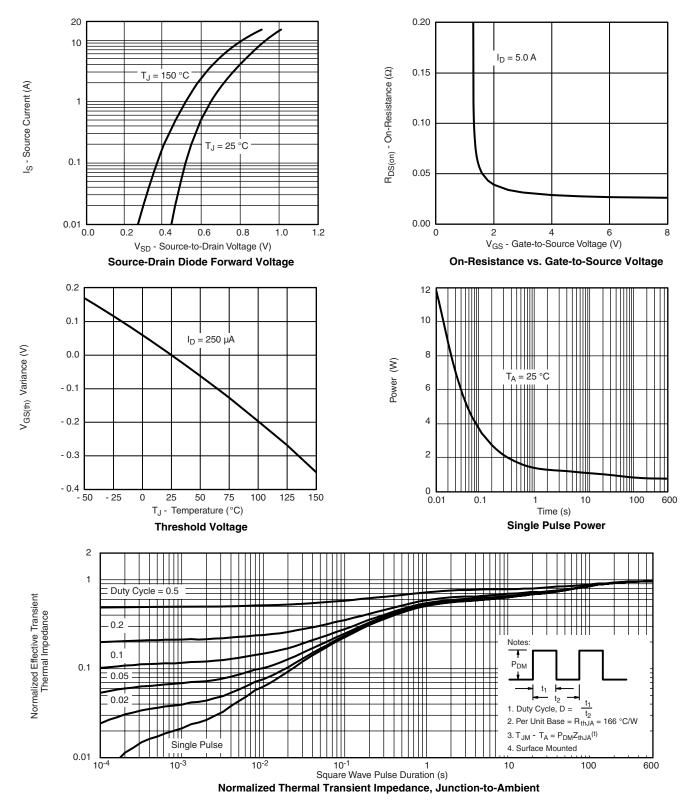
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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## SOT-23 (TO-236): 3-LEAD







Dim	MILLI	METERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A <sub>1</sub>	0.01	0.10	0.0004	0.004	
A <sub>2</sub>	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E <sub>1</sub>	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e <sub>1</sub>	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L <sub>1</sub>	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
FCN: S-03946-Rev K 09-	lul-01	•			

ECN: S-03946-Rev. K, 09-Jul-01

DWG: 5479

Document Number: 71196 www.vishay.com 09-Jul-01



### **RECOMMENDED MINIMUM PADS FOR SOT-23**



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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